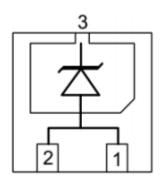


Description

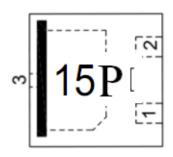
The JS15U1GD50-3 is a 15V Uni-directional TVS diode, utiliz-ing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensi-tive data and power line. The JS15U1GD50-3 complies with the IEC 61000-4-2 (ESD) standard with ±30 kV air and ±30kV contact discharge. It is assembled into an ultra-small lead-free DFN2020-3 package. The small size and high ESD surge protection make JS15U1GD50-3 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Circuit Diagram



Circuit and Pin Schematic

Marking Diagram



Transparent top view

15P:Device Marking Code

Features

- * 5900W peak pulse power (8/20μs)
- Low leakage:nA level
- * Operating voltage: 15V
- Ultra low clamping voltage
- * One power line protects
- * Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV

Contact discharge: ±30kV

- IEC61000-4-5 (Lightning) 175A (8/20μs)
- * RoHS Compliant

* Package: DFN2020-3

Applications

- * Fast-charge battery chargers
- * Power management system
- * Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras

Ordering Information

Part Number	Packaging	Reel Size
JS15U1GD50-3	3000/Tape & Reel	7 inch



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

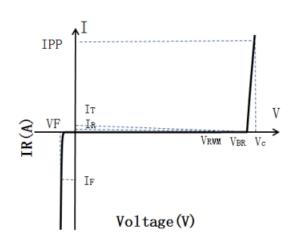
Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20μs)	Power (8/20µs) Ppk		W	
Peak Pulse Current (8/20µs) IPP		175	A	
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV	
ESD per IEC 61000-4-2 (Contact)	VESD	±30		
Operating Temperature Range	TJ	-55 to +125	°C	
Storage Temperature Range	Tstg	-55 to +150	°C	

Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Reverse Working Voltage	VRWM				15.0	V
Breakdown Voltage	VBR	$I_T = 1 \text{mA}$	16		19	V
Reverse Leakage Current	I_R	$V_{RWM} = 15V$			20	uA
Clamping Voltage	Vc	$I_{PP} = 100A (8 \times 20 \mu s \text{ pulse})$			27	V
Clamping Voltage	Vc	I _{PP} = 175A (8 x 20μs pulse)			34	V
Junction Capacitance	Сл	VR = 0V, f = 1MHz		1100		pF

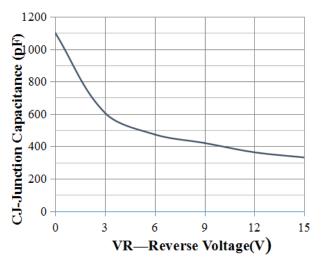
Portion Electronics Parameter

Symbol	Parameter	
IT	Test Current	
Ірр	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @Ic	

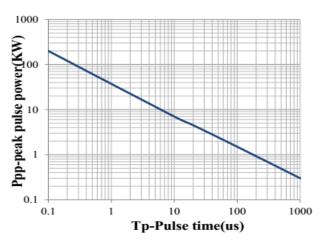




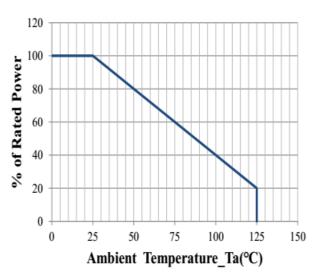
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



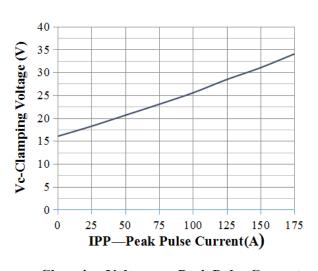
Junction Capacitance vs. Reverse Voltage



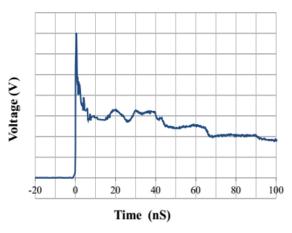
Peak Pulse Power vs. Pulse Time



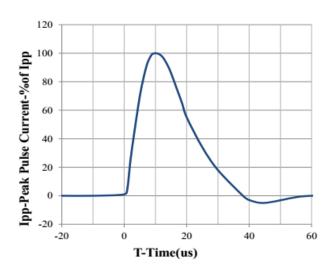
Power Derating Curve



Clamping Voltage vs. Peak Pulse Current



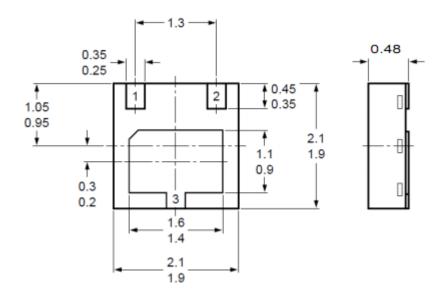
IEC61000-4-2 Pulse Waveform



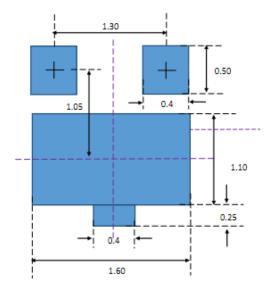
8 X 20us Pulse Waveform



DFN2020-3 Package Outline Drawing (Dimensions in millimeters)



Suggested Land Pattern



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